1.0 General Description

IW7700A is a synchronous rectifier for Flyback converters. It integrates a 40V power MOSFET that can replace Schottky diode for high efficiency. It turns on the internal MOSFET if the V_{SW}<-500mV and turns it off before the current from GND to SW is lower than zero.

Features

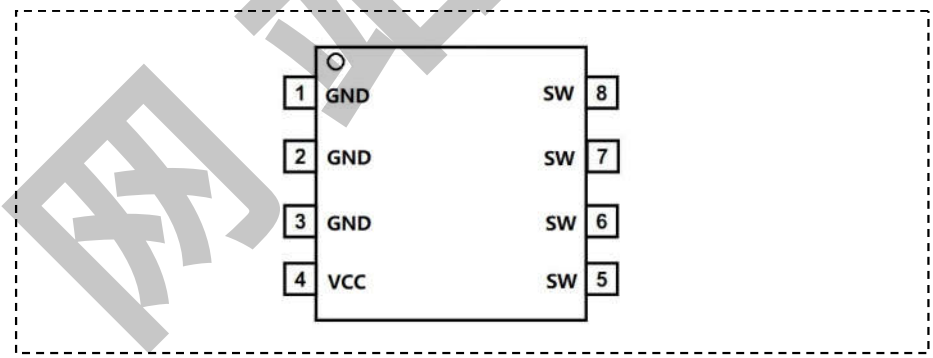
- Supports DCM and Quasi-Resonant Flyback converter
- Supports High-side and Low-side ectification
- Integrated 15mΩ 40V Power MOSFET
- No need external power supply

Applications

- Flyback converters
- Adaptors

2.0 Products Information

2.1 Pin configuration



IW7700A（8 Lead SOIC-8 Package）

Pin#	Name	Description
1、2、3	GND	Ground.
4	VCC	Power supply, Bypass a capacitor between VCC and GND.
5、6、7、8	SW	Inernal Power MOSFET Drain.

2.2 Marking Information

Part Number	Marking Information
IW7700A	

2.3 Table of Standard Tape and Reel Configurations

Part Number	Package Description	Quantity/Reel
IW7700A	SOP8，Halogen-free，T&R	4000 pcs

2.4 Block diagram

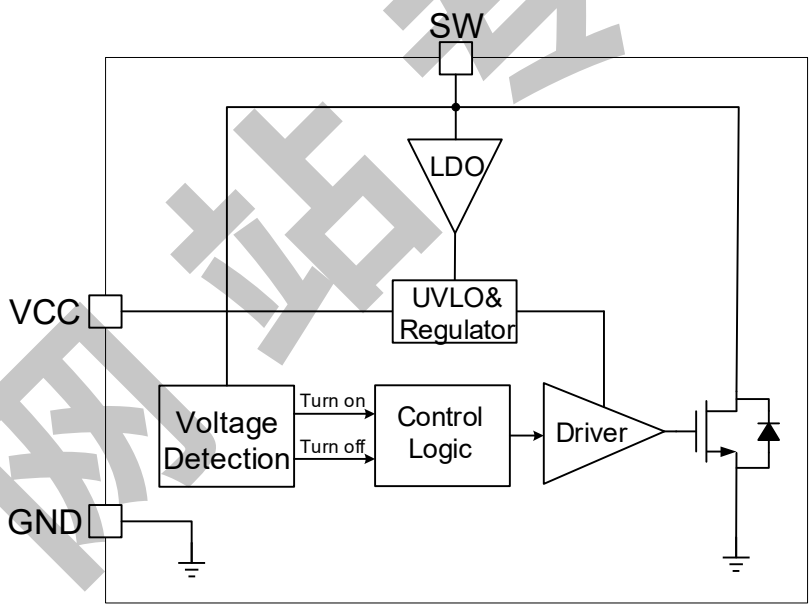


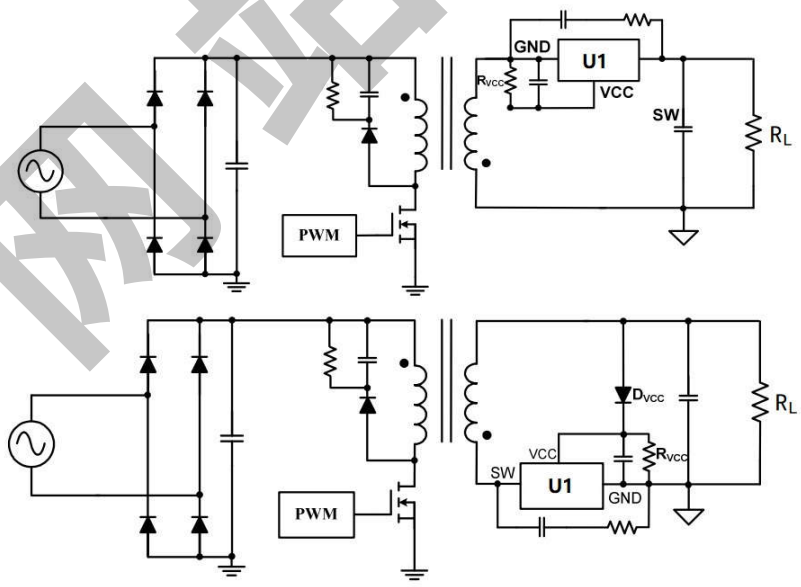
Figure2.1 IW7700A Functional Block Diagram

3.0 Performance

Absolute Maximum Rating	Symbol	Value	Units
SW PIN		40	V
VCC PIN		15	V
Maximum Power Dissipation		2.5	W
Junction Temperature		150	℃
Lead Temperature		260	℃
Storage Temperature		-65 to 150	℃
ESD Susceptibility（Human Body Mode）		2000	V
Recommended Operating Conditions	**Symbol**	**Value**	**Units**
SW PIN	SW	20 to 35	V
VCC PIN	VCC	7 to 9	V
Operation Junction Temp.		-40 to 125	℃
Thermal Performance	**Symbol**	**Value**	**Units**
SOP8	θ_{JA}	95	/W
SOP8	θ_{JC}	45	/W

4.0 Typical Application

The IW7700A contains a controller for a flyback circuit.



Note1：R_{VCC} is recommended in case IC is damaged in CCM.

Note2：D_{VCC} is recommended if VCC voltage is too low in light load.

5.0 Electrical Characteristics

(TA = 25℃, unless otherwise noted)

Symbol	Parameter	Test Conditions	Min	Typ	Max	Unit
VCC SECTION						
V_{CC}	VCC Voltage	SW=40V，VCC with 0.1uF	7.4	7.8	8.1	V
V_{CC_ST}	VCC startup voltage		3.6	3.8	4.0	V
V_{CC_UVLO}	VCC UVLO		3.5	3.65	3.8	V
I_Q	Quiescent Current	VCC=6V,C_{VCC}=0.1uF	70	85	100	uA
Internal MOS Section						
R_{DSON}	Internal MOS Rdson	VCC=10V，I_{SW}=20A		15		mΩ
I_{PEAK}	Maximum Peak Current	T_J = 25℃		30		A
T_B	Turn on Blanking Time			500		nS
T_{ON_DELAY}	Internal MOS turn on delay			24		nS
T_{OFF_DELAY}	Internal MOS turn off delay			10		nS
T_{ON_MIN}	MOS Minimum on time			1		uS
T_{OFF_MIN}	MOS Minimum off time			3		uS
SW SECTION						
V_{TURNON}	Internal MOS turn on Threshold			-0.5		V
$V_{(BR)DSS}$	Drain to Source Breakdown Voltage	VCC=9V，I_{SW}=250uA	40			V

6. Theory of Operation

6.1 Operation

IW7700A is a synchronous rectifier, it can replace the Schottky to improve the efficiency in Flyback converters. It supports operation in DCM and Quasi-Resonant Flyback converters. It can power itself through the internal LDO during the turn-off period, a 0.1uF capacitor is needed between VCC and GND.

6.2 Startup and Under-Voltage Lockout (UVLO)

During the startup period, when the VCC is increases to V_{CC_ST}, the chip starts to work.When the VCC is below UVLO threshold, the internal MOSFET is turned off and the current flows though body diode until the VCC exceeds the startup voltage.

6.3 Turn-on Blanking Time

The control circuitry contains a blanking function. When the internal power MOSFET is turned on, it at least last for some time, the turn on blanking time is about 500ns. During the turn on blanking period, the turn off threshold is not totally blanked, but changes the threshold current. This assures that the internal MOSFET can always be turned off even during the blanking period.

6.4 Turn On Phase

The switch current first flows through the body diode of integrate power MOSFET, which generates a negative V_{SW}. When the V_{SW} is higher than 0.7V and then V_{SW} is lower than V_{TURNON}, it turns on the integrate MOSFET after 100ns delay.

6.5 Turn Off Phase

The IW7700A senses the current of the internal MOSFET I_{SW}, before I_{SW} is lower than Internal MOS turn off threshold, the driver voltage of the switch is pulled down to zero after 10ns delay.

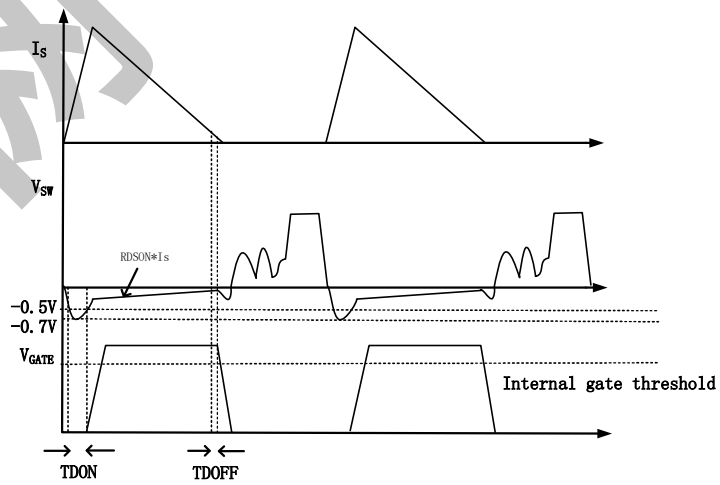


Figure6.1 Turn on and turn off dalay

6.7 RC Snubber Circuit

In some applications (output short circuit protection), the inductor current may go into slight CCM condition. To avoid the voltage spike across the synchronous rectifier, we suggest RC snubber should be placed between SW and GND, and a resistor should be paralleled with VCC capacitor.

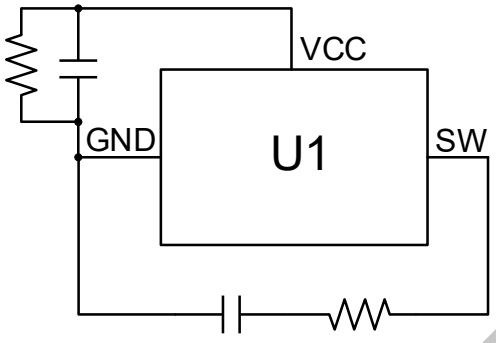


Figure6.2 RC Snubber circuit

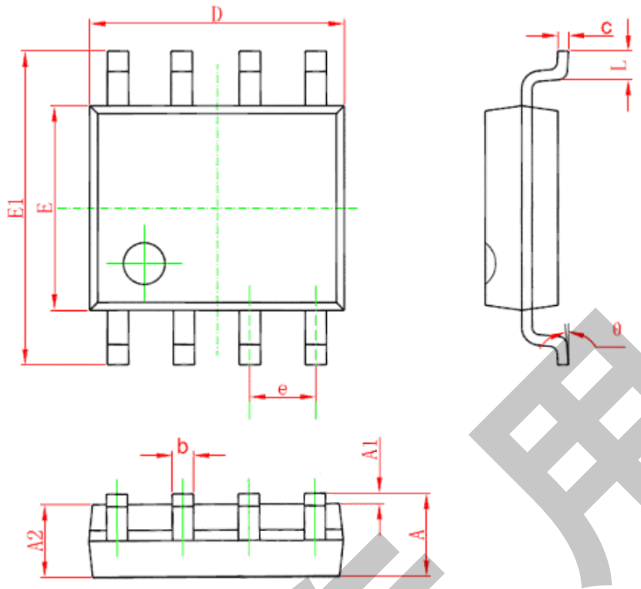
6.8 PCB Layout Guidelines

The VCC pin must be locally bypassed with a capacitor.

7. Package Information

SOP8

8-Pin Plastic SOP



Symbol	Dimension in Millimeters		Dimensions in Inches	
	Min	Max	Min	Max
A	1.350	1.750	0.053	0.069
A1	0.050	0.250	0.002	0.010
A2	1.250	1.650	0.049	0.065
b	0.310	0.510	0.012	0.020
c	0.100	0.250	0.004	0.010
D	4.700	5.150	0.185	0.203
E	3.800	4.000	0.150	0.157
E1	5.800	6.200	0.228	0.244
e	1.270(BSC)		0.050(BSC)	
L	0.400	1.270	0.016	0.050
θ	0°	8°	0°	8°

Data and specifications subject to change without notice.

This product has been designed and qualified for Industrial Level and Lead-Free.

Qualification Standards can be found on GS's Web site.

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